

1.5A, 50V - 600V Glass Passivated High Efficient Rectifier

FEATURES

- Glass passivated chip junction
- High efficiency, Low V_F
- High current capability
- High surge current capability
- Low power loss
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor

MECHANICAL DATA

- Case: DO-204AC (DO-15)
- Molding compound meets UL 94V-0 flammability rating
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.4 g (approximately)

KEY PARAMETERS					
PARAMETER	PARAMETER VALUE U				
I _{F(AV)}	1.5	Α			
V_{RRM}	50 - 600	V			
I _{FSM}	50 A				
T_{JMAX}	150 °C				
Package	DO-204AC (DO-15)				
Configuration	Single die				





DO-204AC (DO-15)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)								
PARAMETER	SYMBOL	HER151	HER152	HER153	HER154	HER155	HER156	UNIT
		G-T	G-T	G-T	G-T	G-T	G-T	
Marking code on thedevice		HER151G	HER152G	HER153G	HER154G	HER155G	HER156G	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	210	280	420	>
Forward current	$I_{F(AV)}$			1	.5			Α
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}		50				А	
Junction temperature T _J		- 55 to +150					ç	
Storage temperature	T_{STG}			- 55 to	o +150			°C

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THERMAL PERFORMANCE							
PARAMETER	SYMBOL	LIMIT	UNIT				
Junction-to- ambient thermal resistance	$R_{\Theta JA}$	60	°C/W				

PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT	
	HER151G-T					
	HER152G-T			_	1.0	V
(1)	HER153G-T			_	1.0	V
Forward voltage per diode (1)	HER154G-T	$I_F = 1.5A, T_J = 25^{\circ}C$	V_{F}			
	HER155G-T			-	1.3	V
	HER156G-T			-	1.7	V
Reverse current @ rated V _R per diode ⁽²⁾		T _J = 25°C		-	5	μA
		T _J = 125°C	- I _R	-	150	μA
	HER151G-T					
	HER152G-T		CJ	35		
I will be a second second	HER153G-T				-	pF
Junction capacitance	HER154G-T	1 MHz, V _R =4.0V				
	HER155G-T					
	HER156G-T			20	-	pF
	HER151G-T					
	HER152G-T					
	HER153G-T	I _F =0.5A,I _R =1.0A	t _{rr}	-	50	ns
Reverse recovery time	HER154G-T	I _{RR} =0.25A				
	HER155G-T					
	HER156G-T			-	75	ns

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION							
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING			
LIEDAE O T	A0	G	DO-15	1,500 / Ammo box			
HER15xG-T (Note 1, 2)	R0		DO-15	3,500 / 13" Paper reel			
(14010-1, 2)	В0		DO-15	1,000 / Bulk packing			

Notes:

- 1. "x" defines voltage from 50V (HER151G-T) to 600V (HER156G-T)
- 2. Whole series with green compound (halogen-free)

EXAMPLE P/N							
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION			
HER151G-T A0G	HER151G-T	A0	G	Green compound			



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

2
(Y)
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RESISTIVE OR
INDUCTIVE LOAD

0
25
50
75
100
125
150

AMBIENT TEMPERATURE (°C)

Fig.2 Typical Junction Capacitance

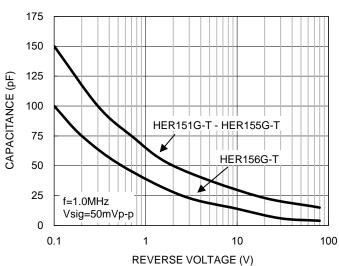


Fig.3 Typical Reverse Characteristics

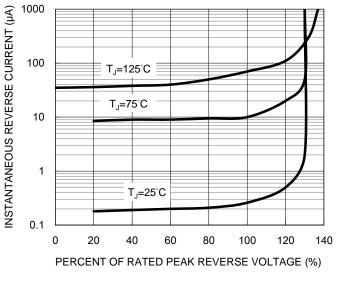
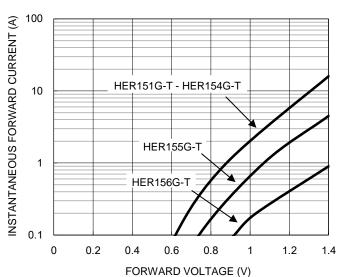


Fig.4 Typical Forward Characteristics





CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.5 Maximum Non-repetitive Forward Surge Current

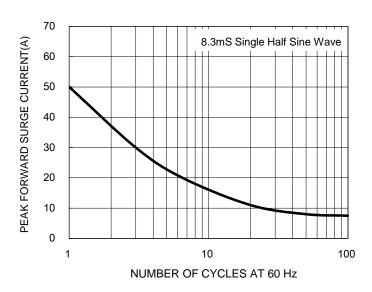
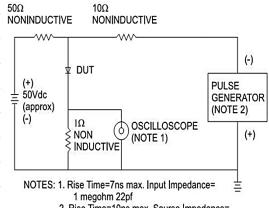
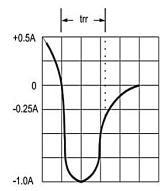


Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram

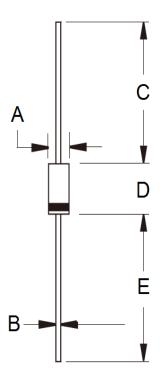






PACKAGE OUTLINE DIMENSIONS

DO-204AC (DO-15)



DIM.	Unit (ı	mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	2.60	3.60	0.102	0.142	
В	0.70	0.90	0.028	0.035	
С	25.40	-	1.000	-	
D	5.80	7.60	0.228	0.299	
Е	25.40	-	1.000	-	

MARKING DIAGRAM



P/N = Marking Code G = Green Compound YWW = Date Code

F = Factory Code



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